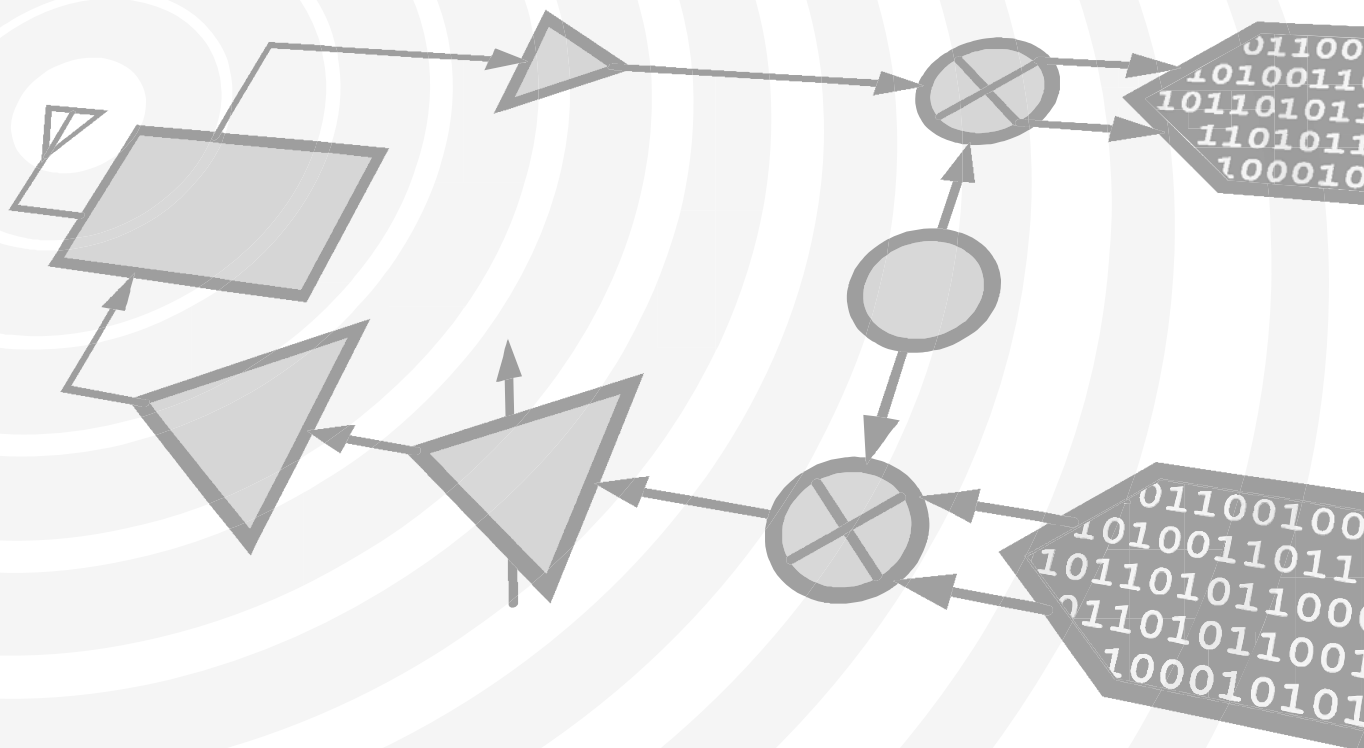




NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



THIS PAGE INTENTIONALLY LEFT BLANK



MICROWAVE CORPORATION v00.0613



HMC545A / 545AE

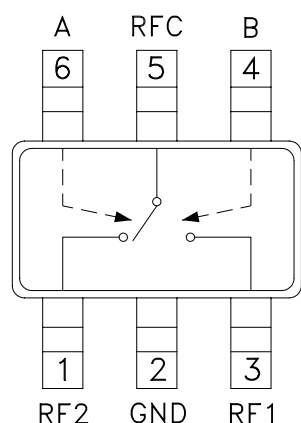
**GaAs MMIC SPDT
SWITCH, DC - 3 GHz**

Typical Applications

The HMC545A / HMC545AE is ideal for:

- Cellular/3G Infrastructure
- Private Mobile Radio Handsets
- WLAN, WiMAX & WiBro
- Automotive Telematics
- Test Equipment

Functional Diagram



Features

- Low Insertion Loss: 0.27 dB
- High Input IP3: +54 dBm
- Low DC Power Consumption
- Positive Control: 0/+3V to 0/+8V
- Ultra Small Package: SOT26

General Description

The HMC545A and HMC545AE are low-cost SPDT switches in 6-lead SOT26 plastic packages for use in general switching applications which require very low insertion loss and very small size. With 0.25 dB typical loss, these devices can control signals from DC to 3.0 GHz and are especially suited for IF and RF applications including Cellular/3G, ISM, automotive and portables. The design provides exceptional insertion loss performance, ideal for filter and receiver switching. RF1 and RF2 are reflective shorts when "Off". The two control voltages require a minimal amount of DC current and offer compatibility with CMOS and some TTL logic families.

Electrical Specifications

$T_A = +25^\circ \text{C}$, $V_{ctl} = 0/+5 \text{ Vdc}$ (Unless Otherwise Stated), 50 Ohm System

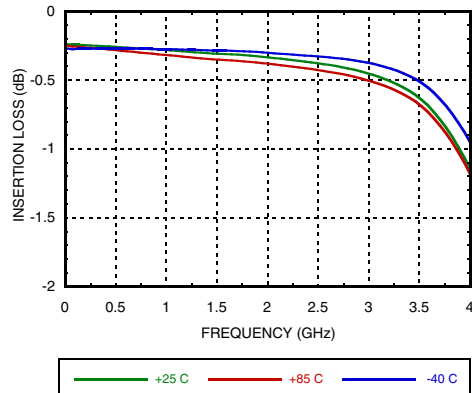
Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	DC - 1.0 GHz		0.27	0.4	dB
	DC - 2.5 GHz		0.3	0.5	dB
	DC - 3.0 GHz		0.4	0.7	dB
Isolation	DC - 2.0 GHz	26	31		dB
	DC - 2.5 GHz	22	26		dB
	DC - 3.0 GHz	19	22		dB
Return Loss	DC - 1.0 GHz		24		dB
	DC - 2.0 GHz		20		dB
	DC - 2.5 GHz		19		dB
	DC - 3.0 GHz		17		dB
Input Power for 1 dB Compression	0.5 - 3.0 GHz	$V_{ctl} = 0/+3V$	20	23	dBm
		$V_{ctl} = 0/+5V$	27	30	dBm
		$V_{ctl} = 0/+8V$	30	33	dBm
Input Third Order Intercept (Two-tone Input Power = +17 dBm Each Tone)	0.5 - 3.0 GHz	$V_{ctl} = 0/+3V$	31		dBm
		$V_{ctl} = 0/+5V$	51		dBm
		$V_{ctl} = 0/+8V$	54		dBm
Switching Characteristics	DC - 3.0 GHz	tRISE, tFALL (10/90% RF)	70		ns
		tON, tOFF (50% CTL to 10/90% RF)	90		ns

For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824

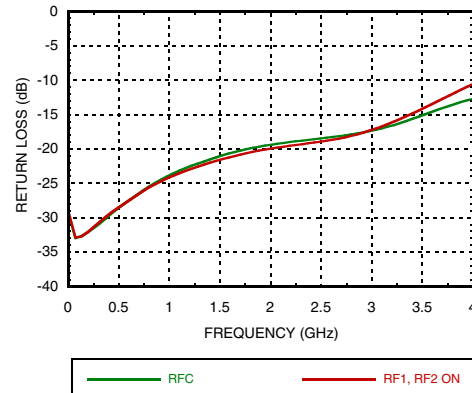
Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com

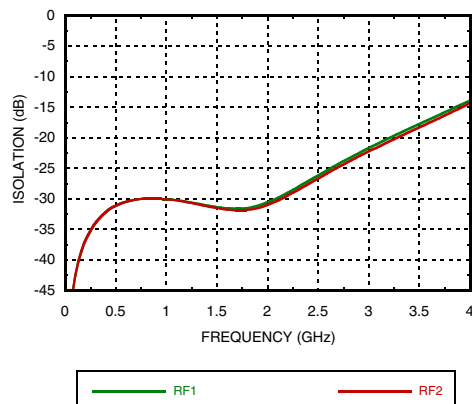
Insertion Loss



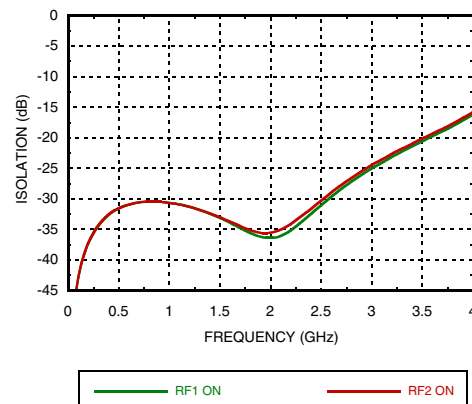
Return Loss



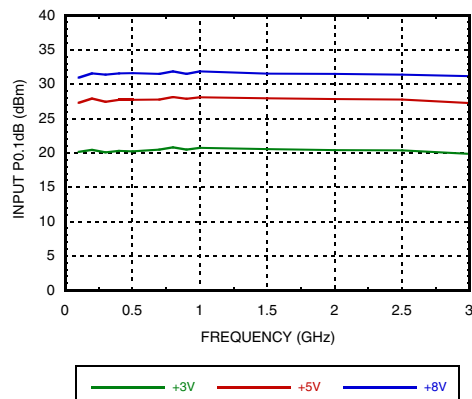
Isolation Between Ports RFC and RF1/RF2



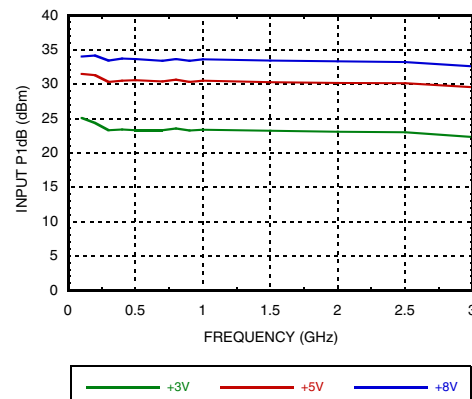
Isolation Between Ports RF1 and RF2



Input P0.1dB vs. Vctl

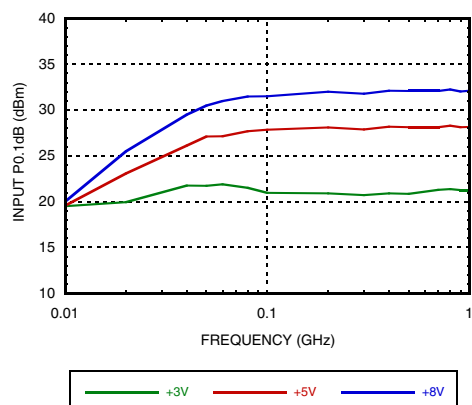
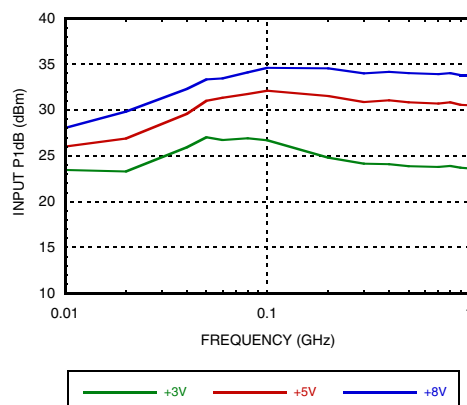
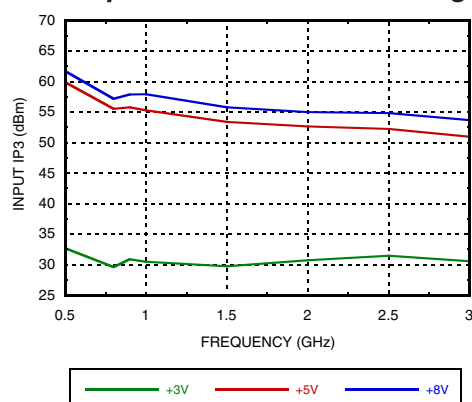


Input P1dB vs. Vctl



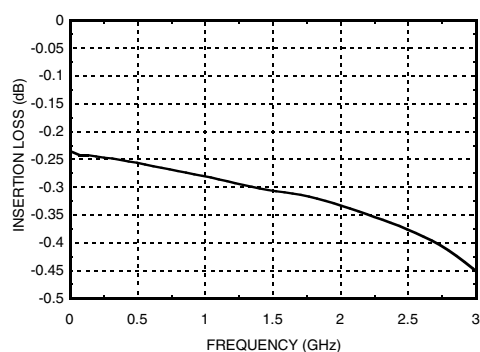


MICROWAVE CORPORATION v00.0613

**HMC545A / 545AE****GaAs MMIC SPDT
SWITCH, DC - 3 GHz****Low Frequency Input P0.1dB vs. Vctl****Low Frequency Input P1dB vs. Vctl****Input Third Order
Intercept Point vs. Control Voltage****Absolute Maximum Ratings**

RF Input Power (Vctl = 0/+8V)	+34 dBm
Control Voltage Range (A & B)	-0.2 to +12 Vdc
Hot Switch Power Level (Vctl = 0/+8V)	+32 dBm
Channel Temperature	150 °C
Continuous P _{diss} (T = 85 °C) (derate 5.6 mW/°C above 85°C)	0.1 W
Thermal Resistance	169°C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

DC blocks are required at ports RFC, RF1 and RF2.

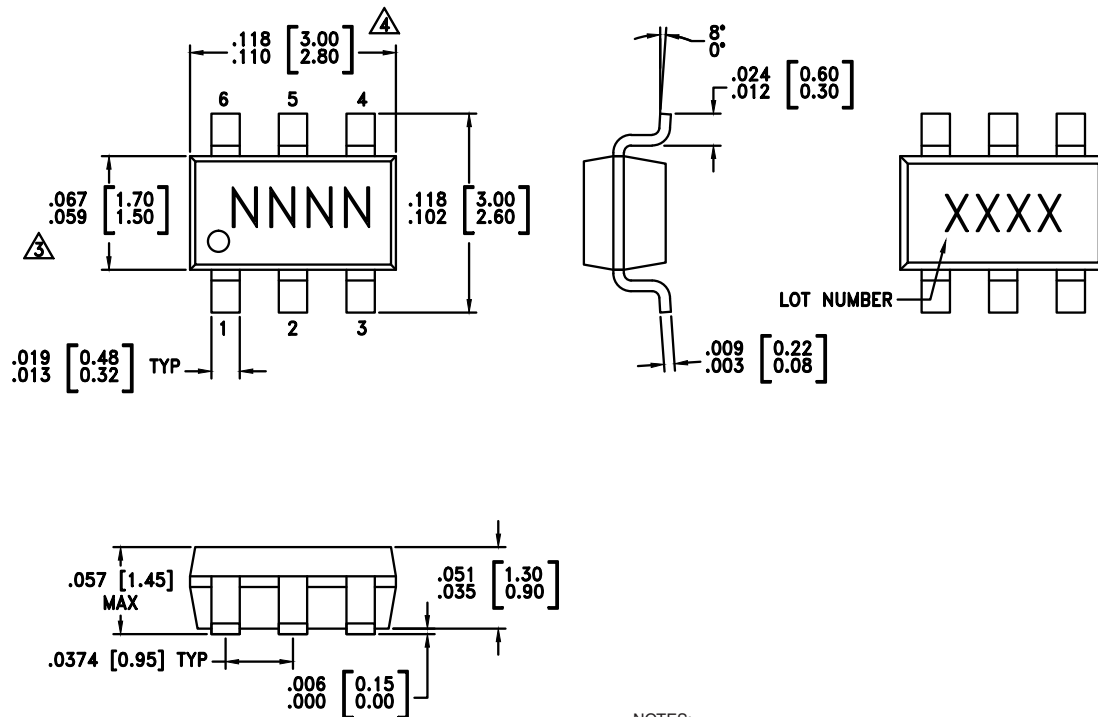
Insertion Loss, T = +25 °C**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS****Truth Table**

Control Input		Control Current	
A	B	RFC to RF1	RFC to RF2
Low	High	Off	On
High	Low	On	Off

Control Voltages

State	Bias Condition
Low	0 to 0.2 Vdc @ 1 μ A Typical
High	+3 Vdc @ 0.5 μ A Typical to +8 Vdc @ 14 μ A Typical (± 0.2 Vdc)

Outline Drawing



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
4. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

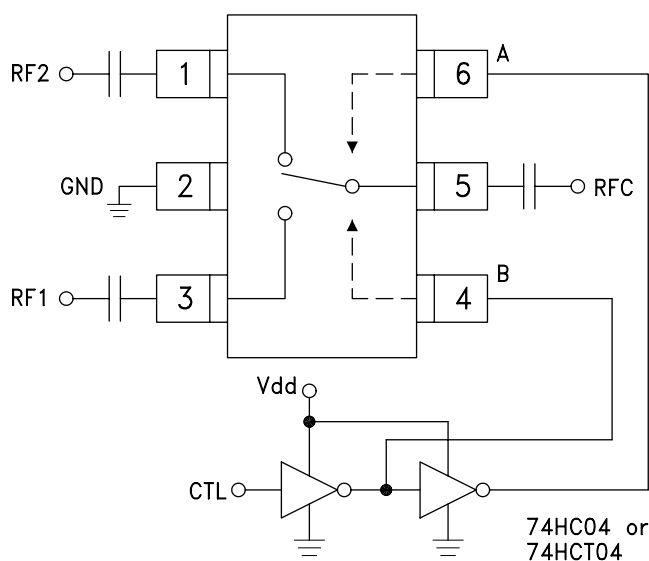
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking
HMC545A	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H545A
HMC545AE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	545AE

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C



MICROWAVE CORPORATION v00.0613

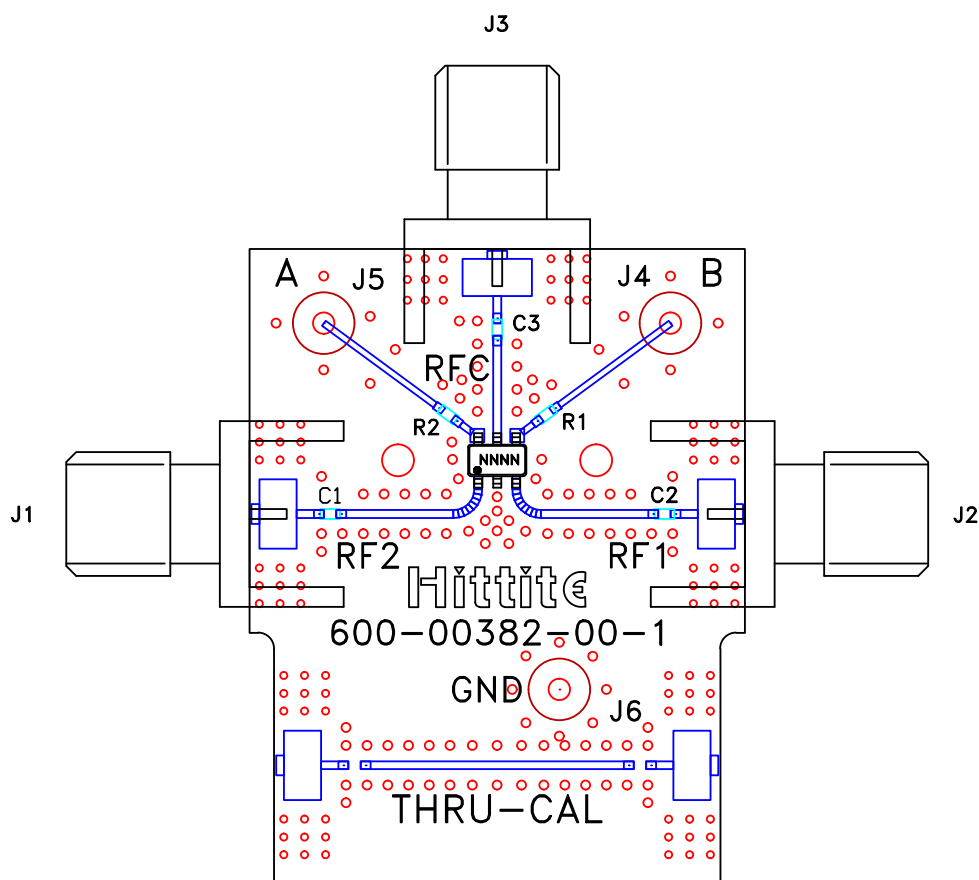
**HMC545A / 545AE****GaAs MMIC SPDT
SWITCH, DC - 3 GHz****Typical Application Circuit****Notes:**

1. Set logic gate Vdd = +3V to +5V and use HCT series logic to provide a TTL driver interface.
2. Control inputs A/B can be driven directly with CMOS logic (HC) with Vdd of +3V to +8V applied to the CMOS logic gates.
3. DC Blocking capacitors are required for each RF port as shown. Capacitor value determines lowest frequency of operation.
4. Highest RF signal power capability is achieved with Vdd = +8V and A/B set to 0/+8V.

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 3, 5	RF2, RF1, RFC	These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
2	GND	This pin must be connected to RF/DC ground.	
4	B	See truth and control voltage tables.	
6	A	See truth and control voltage tables.	

Evaluation PCB



List of Materials for Evaluation PCB EV1HMC545A ^[1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
J4 - J6	DC Pin
R1 - R2	1K Ohm resistor, 0402 Pkg.
C1 - C3	330 pF capacitor, 0402 Pkg.
U1	HMC545A / HMC545AE SPDT Switch
PCB ^[2]	101659 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 Ohm impedance and the package ground leads should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.